Miniature Reflective Object Sensor

Features

- Phototransistor Output
- No Contact Surface Sensing
- Miniature Package
- Lead Form Style: Gull Wing
- Two Leadform Options:
 - ◆ Through Hole (QRE1113)
 - SMT Gull Wing (QRE1113GR)
- Two Packaging Options:
 - ◆ Tube (QRE1113)
 - ◆ Tape and Reel (QRE1113GR)

MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
T _{OPR}	Operating Temperature	-40 to +85	°C
T _{STG}	Storage Temperature	perature -40 to +90	
T _{SOL-I}	Soldering Temperature (Iron) (Notes 2, 3, 4)	240 for 5 s	°C
T _{SOL-F}	Soldering Temperature (Flow) 260 for (Notes 3, 4)		°C

EMITTER

I _F	Continuous Forward Current	50	mA
V _R	Reverse Voltage	5	V
I _{FP}	Peak Forward Current (Note 5)	1	Α
P_{D}	Power Dissipation (Note 1)	75	mW

SENSOR

V_{CEO}	Collector-Emitter Voltage	30	V
V _{ECO}	Emitter-Collector Voltage	5	V
I _C	Collector Current	20	mA
P_{D}	Power Dissipation (Note 1)	50	mW

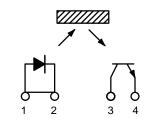
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Derate power dissipation linearly 1.00 mW/°C above 25°C.
- 2. RMA flux is recommended.
- 3. Methanol or isopropyl alcohols are recommended as cleaning agents.
- 4. Soldering iron 1/16" (1.6 mm) from housing.
- 5. Pulse conditions: $tp = 100 \mu s$; T = 10 ms.



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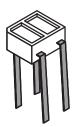
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Pin 1: Anode Pin 2: Cathode Pin 3: Collector Pin 4: Emitter



REFLECTIVE RECTANGULAR SURFACE MOUNT CASE 100CY



REFLECTIVE RECTANGULAR THROUGH HOLE CASE 100AQ

ORDERING INFORMATION

	<u> </u>			
Device	Package	Shipping [†]		
QRE1113	Reflector Regulator (Surface Mount)	1600 / Tube		
QRE1113GR	Reflector Regulator (Through Hole)	1000 / Tape & Reel		

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ELECTRICAL/OPTICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
INPUT DIO	DE					
V _F	Forward Voltage	I _F = 20 mA		1.2	1.6	V
I _R	Reverse Leakage Current	V _R = 5 V			10	μΑ
λ _{PE}	Peak Emission Wavelength	I _F = 20 mA		940		nm
OUTPUT T	RANSISTOR					
Ι _D	Collector-Emitter Dark Current	$I_F = 0 \text{ mA}, V_{CE} = 20 \text{ V}$			100	nA
COUPLED						
I _{C(ON)}	On-State Collector Current	I _F = 20 mA, V _{CE} = 5 V (Note 6)	0.10	0.90		mA
I _{CX}	Cross-Talk Collector Current	I _F = 20 mA, V _{CE} = 5 V (Note 7)			1	μΑ
V _{CE(SAT)}	Saturation Voltage				0.3	V
t _r	Rise Time	V_{CC} = 5 V, $I_{C(ON)}$ = 100 μA, R_L = 100 kΩ		20		μs
t _f	Fall Time	1		20		μS

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

6. Measured using an aluminum alloy mirror at d = 1 mm.

7. No reflective surface at close proximity.

REFLOW PROFILE

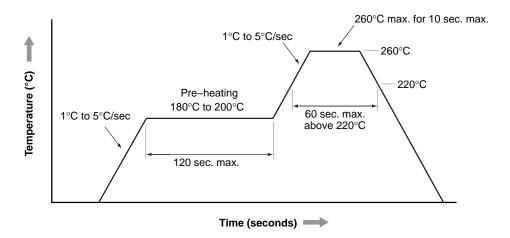


Figure 1. Reflow Profile

TYPICAL PERFORMANCE CURVES

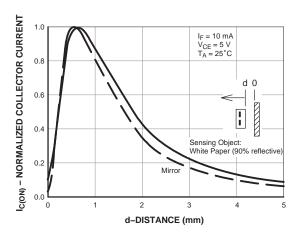


Figure 2. Normalized Collector Current vs. Distance between Device and Reflector

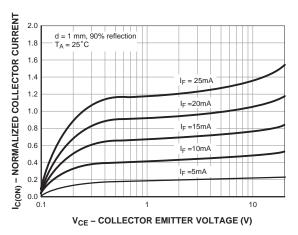


Figure 4. Normalized Collector Current vs. Collector to Emitter Voltage

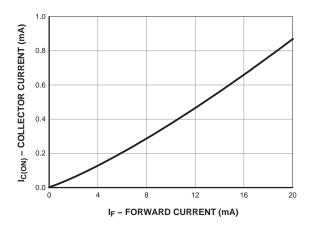


Figure 3. Collector Current vs. Forward Current

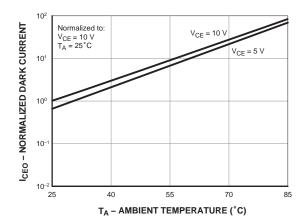


Figure 5. Collector Emitter Dark Current (Normalized) vs. Ambient Temperature

TYPICAL PERFORMANCE CURVES (Continued)

100

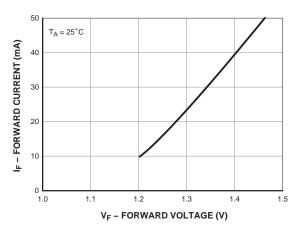
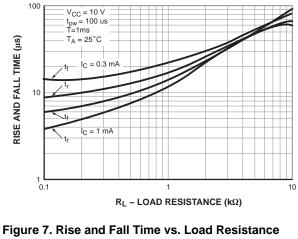


Figure 6. Forward Current vs. Forward Voltage



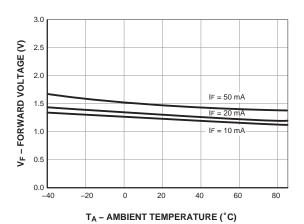


Figure 8. Forward Voltage vs. Ambient **Temperature**

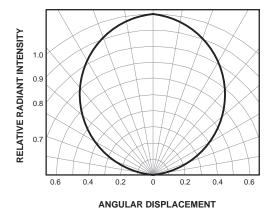


Figure 9. Radiation Diagram

TAPING DIMENSIONS FOR GR OPTION

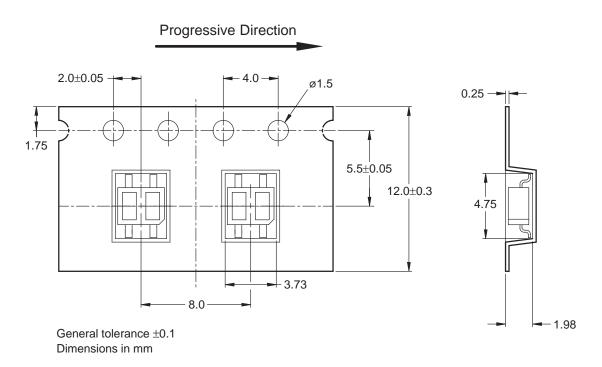


Figure 10. Taping Dimensions for GR Option

REEL DIMENSIONS

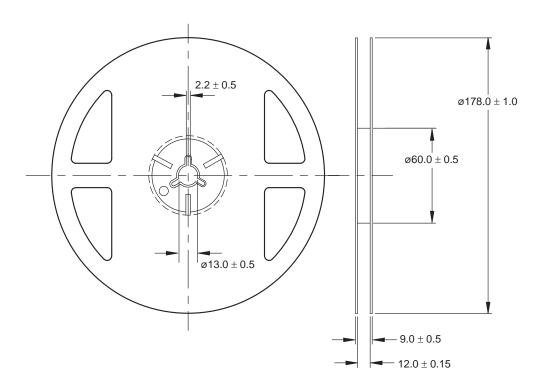
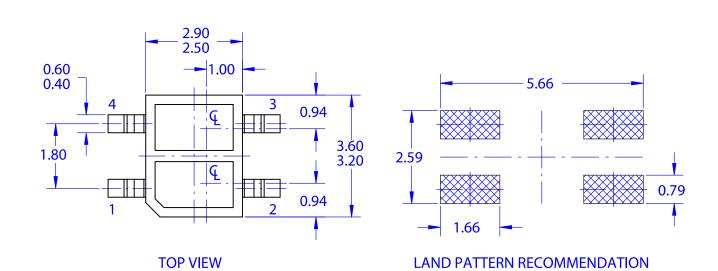
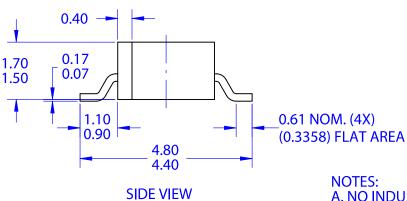


Figure 11. Reel Dimensions

PACKAGE DIMENSIONS

ARUSM-313 / REFLECTIVE RECTANGULAR SURFACE MOUNT CASE 100CY ISSUE O



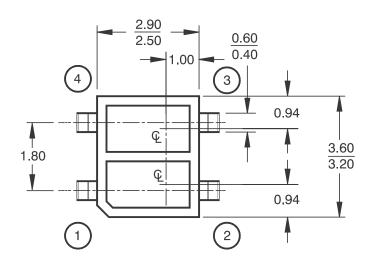


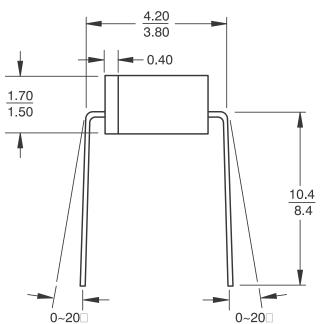
A. NO INDUSTRY STANDARD APPLIES
TO THIS PACKAGE
B. ALL DIMENSIONS ARE IN MILLIMETERS
C. TOLERANCE OF ±0.15MM ON ALL
NON-NOMINAL DIMENSIONS

PACKAGE DIMENSIONS

REFLECTIVE RECTANGULAR THROUGH HOLE CASE 100AQ

CASE 100AQ ISSUE O





Notes:

- 1. Dimensions for all drawings are in millimeters.
- 2. Tolerance of ±0.15mm on all non-nominal dimensions

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